

6MBI 15F-120

IGBT MODULE (F series)

■ Features

- ◆ Low Saturation Voltage
- Voltage Drive
- Variety of Power Capacity Series

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Outline Drawings

CASE

UL

■ Maximum Ratings and Characteristics

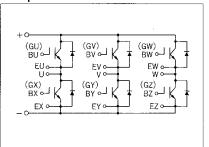
Absolute Maximum Ratings

ltems		Symbols	Ratings	Units	
Collecter-Emitter Voltage		Vces	1200	V	
Gate-Emitter Voltage		Vges	±20	V	
	Continuous Ic	lc	15	А	
Collecter Current	1ms	IC pulse	30		
	Continuous	-lc	15		
	1ms	-IC pulse	30		
Max. Power Dissipation		Pc	120	W	
Operating Temperature		Ti	+150	°C	
Storage Temperature		Tstg	40 to +125	°C	
Net. Weight			235	g	
Isolation Voltage	AC. 1min.	Visol	2500	V	
Community of the commun		Mounting *1	3.5 {35}	N·m	
Screw Torque		Terminals		{kg · cm	

■ Equivalent Circuit Schematic

M607

E82988(M)



• Electrical Characteristics (Tc=25°C)

Items	Symbols	Test Conditions		Min.	Тур.	Max.	Units
Zero Gate Voltage Collecter Current	Ices	VgE=0V VcE=1200V Tj=25°C				1.0	mA
		VgE=0V VcE=1200V Tj=125°C					mA
Gate-Emitter Leackage Current	lges	Vce=0V Vge=±20V				100	nΑ
Gate-Emitter Threshold Voltage	VGE (th)	VcE=20V Ic=15mA		3.0		6.0	V
Collecter-Emitter Saturation Voltage	VCE (sat)	VGE=15V Ic=15A				2.5	V
Input Capacitance	Cies	VgE=0V VcE=10V f=1MHz			2700		pF
Output Capacitance	Coes						
Reverse Transfer Capacitance	Cres						
T T'	ton	Vcc=600V	Resitive load			8.0	μз
Turn-on Time	tr	lc=15A				0.6	
T (CT)	toff	Vge=±15V	Inductive load			1.5	
Turn-off Time	tr	Rg=82Ω				1.0	
Diode Forward On-Voltage	VF	IF=15A, VGE=0V				2.5	V
Reverse Recovery Time	trr	I _F =15A, -di/dt=50A/μs V _{GE} =-10V				350	ns

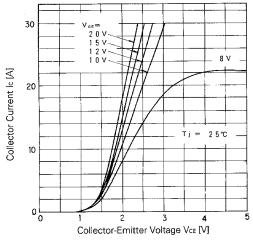
• Thermal Characteristics

ltems	Symbols	Test Conditions	Min.	Тур.	Max.	Units	
	Rth (j-c)	IGBT			1.04		
Thermal Resistance	Rth (j-c)	Diode			2.01	°C/W	
	Rth (c-f)	With Thermal compound		0.06			

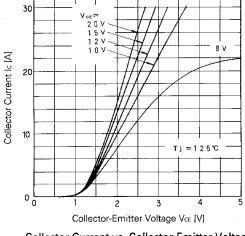
^{*1} Recommendable Value 2.5 to 3.5 N*m {25 to 35 kg*cm] (M5)



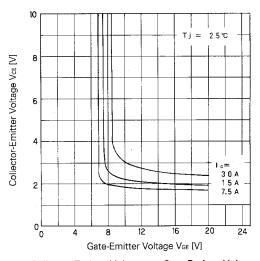




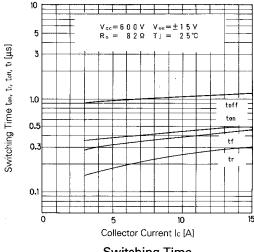
Collector Current vs. Collector-Emitter Voltage



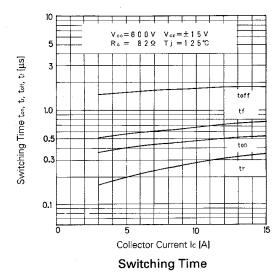
Collector Current vs. Collector-Emitter Voltage

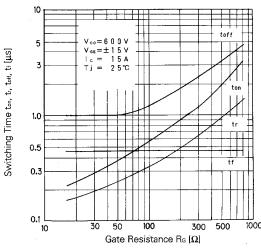


Collector-Emitter Voltage vs. Gate-Emitter Voltage



Switching Time

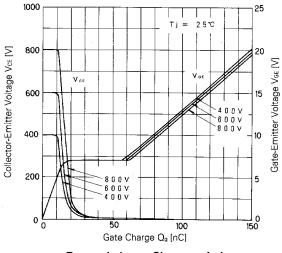




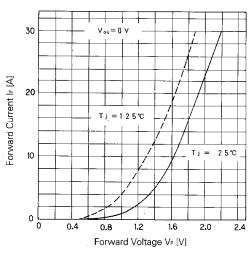
Switching Time-Gate Resistance



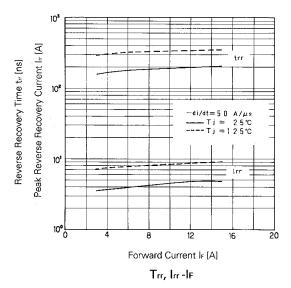




Dynamic Input Characteristic



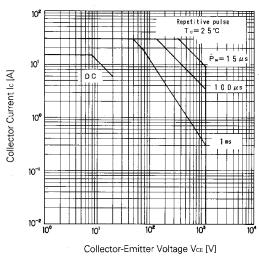
Forward Voltage of Free Wheel Diode



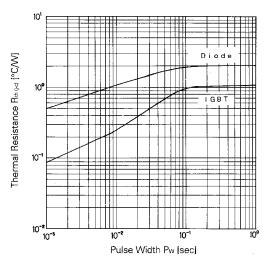
T_{j=25°C}
+V_{α∈315}V
-V_{α∈315}V
R_{α=82Ω}
10°
0 500 1000 1500

Collector-Emitter Voltage VcE [V]

Reverse Biased Safe Operating Area



Safe Operating Area



Transient Thermal Resistance

For more information, contact:

Collmer Semiconductor, Inc. P.O. Box 702708 Dallas, TX 75370 972-233-1589 972-233-0481 Fax http://www.collmer.com